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OPEN Characterizing temperaturedependent optical properties of (MA_{0.13}FA_{0.87}) PbI₃ single crystals using spectroscopic ellipsometry

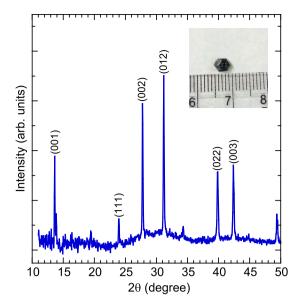
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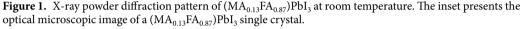
In this paper, we present spectroscopic ellipsometry measurements of (MA_{0.13}FA_{0.87})PbI₃ single crystals assessed at photon energies of 0.73–6.42 eV and at temperatures between 4.4 and 400 K. At room temperature, the refractive index was dispersed as a function of frequency, which is typical of a semiconductor. The absorption spectrum exhibited several electronic transitions. We estimated a room temperature direct band gap of 1.66 ± 0.02 eV and exciton binding energy of 40 meV. With decreasing temperature, the refractive index increased. The room-temperature thermo-optic coefficients were $-1.7 imes 10^{-4}$ and $-2.5 imes 10^{-4}$ K $^{-1}$ at wavelength of 600 and 1200 nm. The exciton peak position and bandgap energy exhibited a redshift, which was attributed to a reverse ordering of the band structures. Additionally, an anomaly in exciton peak position and bandgap occurred at approximately 100–200 K due to the structural phase transition. This phenomenon was associated with the coexistence of MA/ FA-disordered and MA/FA-ordered domains. Our results provide a foundation for the technological development of lead halide perovskites-based photonic devices at various temperatures.

Hybrid organic-inorganic lead halide perovskites have revolutionized the field of solution-processed photovoltaics¹⁻³. The power conversion efficiencies of perovskite solar cells have been significantly improved, reaching up to 22.7%⁴. Large-scale commercialization of perovskite solar cells is possible pending the enhancement of the relevant material's long-term stability in ambient conditions. Among the relevant materials, methylammonium lead triiodide (MAPbl₃) and formamidinium lead triiodide (FAPbl₃) have been most widely investigated. Studies have indicated that MAPbI₃ exhibits thermal and moisture-related instabilities^{5,6}. Due to these humidity-related and thermal instabilities of the constituents of MAPbI₃, the unit cell of the perovskite breaks down and the constituents disintegrate to form other species, leading to the loss of the desirable photovoltaic properties. Regarding FAPbI₃, studies have indicated that this material easily transforms into a yellow nonperovskite hexagonal structure^{6,7}. A compositional engineering technique has been developed to enhance the stability of perovskite materials⁸. Specifically, MAPbI₃ has been incorporated into FAPbI₃, resulting in a stabilized perovskite phase that improves device efficiency and stability. $(FAPbI_3)_{1-x}(MAPbI_3)_x$ material system shows a maximum power conversion efficiency value of 17.3% which was attributed to the increased short-circuit current density and fill factor⁸. The strong diffraction peak at 13.9° remains even after annealing the $(FAPbI_3)_{1-x}(MAPbI_3)_x$ film at 100 °C, which indicated the enhanced phase stability and crystallinity. Ab initio simulations also delivered a higher decomposition reaction energy for this perovskites⁹. Recent stability tests demonstrated a long lifetime more than 30 days of the device based on mixed organic cation based perovskite¹⁰.

For many of the practical applications of these materials, comprehensive studies of their optical properties are essential^{11,12}. Furthermore, the temperature dependence of optical constants is a critical reference for determination of the effects of self-heating on device performance. Foley et al.¹³ examined the temperature-dependent photoluminescence, ultraviolet photoemission, and optical absorption spectra of MAPbI3 thin films. They discovered that the photoluminescence peak position and bandgap energy exhibited a redshift when temperature decreased from 358 to 301 K. This effect was attributed to the difference between the shifts of valence band maximum and conduction band minimum. Wright et al.¹⁴ and Dar et al.¹⁵ studied the temperature-dependent photoluminescence spectra of MAPbI₃, MAPbBr₃, FAPbBr₃, and FAPbI₃ thin films. The photoluminescence peak positions

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of these lead halide thin films exhibited a redshift as temperature decreased. Additionally, anomalous behavior of photoluminescence peak positions was observed at temperatures lower than 150 K due to structural phase transition. Jiang *et al.*¹⁶ studied the temperature-dependent spectroscopic ellipsometry spectra of MAPbI₃ thin film. As temperature decreased, both the dielectric function and absorption spectra exhibited anomalies during the structural phase transition. Wu *et al.*¹⁷ reported the room-temperature photoluminescence and absorption spectra of MA(EA)PbI₃ and FA(MA)PbI₃ single crystals. They reported the values of bandgap energy for FA(MA) PbI₃ and MA(EA)PbI₃ as 1.46 and 1.49 eV.

Most optical measurements of lead halide perovskites have been limited to polycrystalline films. The temperature-dependent optical properties of lead halide perovskites single crystals have not been reported. In this study, we conducted a comprehensive optical study of $(MA_{0.13}FA_{0.87})PbI_3$ single crystals by using spectroscopic ellipsometry. The aim of the present study was to determine the temperature variation of the optical constants and the electronic structures of these materials.

Experiment

Single crystals of $(MA_{0.13}FA_{0.87})PbI_3$ were prepared using an inverse temperature crystallization method. One molar perovskite precursor solution was prepared in γ -butyrolactone containing 0.027 g of cesium methylammonium iodide, 0.1427 g of formamidinium iodide, and 0.461 g of lead(II) iodide. The precursor was maintained in a vial in an oil bath at 88–91 °C under an ambient condition. $(MA_{0.13}FA_{0.87})PbI_3$ single crystals with the (001) surface were approximately 5 mm in diameter, as depicted in the inset of Fig. 1. Crystals of the same batch were characterized using x-ray powder diffraction. X-ray diffractometry data were obtained using a Philips X'pert Pro MRD diffractometer (Cu K α radiation, λ = 0.15418 nm). The photoluminescence spectrum was recorded using a spectrometer (tecSpec MMS) with a 405-nm laser as an excitation source.

Room temperature spectroscopic ellipsometric measurements were conducted under angles of incidence between 60° and 75° and over a spectral range of 0.73 to 6.42 eV using a Woollam M-2000U ellipsometer. For the temperature-dependent measurements, the sample was placed in an ultrahigh-vacuum continuous-flow helium cryostat, enabling measurements at temperatures of 4.4–400 K. Due to the 70° angle of the two cryostat windows, only a single angle of incidence is possible. The raw ellipsometry data Ψ and Δ are related to the complex Fresnel reflection coefficients for light polarized parallel (R_p) and perpendicular (R_s) to the plane of incidence

$$\tan \Psi e^{i\Delta} = \frac{R_p}{R_s}.$$
(1)

To determine the complex refractive index of $(MA_{0.13}FA_{0.87})PbI_3$ single crystal, the experimental data were processed using a three medium optical model consisting of single crystal/surface roughness/air ambient structure. Then the error function σ was minimized in the entire spectral range

$$\sigma^{2} = \frac{1}{m} \sum_{i=1}^{m} [(\Delta_{\exp} - \Delta_{calc})^{2} + (\Psi_{\exp} - \Psi_{calc})^{2}],$$
(2)

where Δ_{calc} , Ψ_{calc} and Δ_{exp} , Ψ_{exp} are, respectively, the calculated and experimental ellipsometric data and m is the number of points in the spectrum. The Lorentz approximation was used to fit the spectral dependence of Ψ and Δ and calculate the complex refractive index. The origin source of this method description can be found in ref.¹⁸

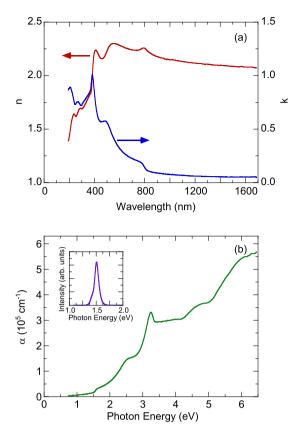


Figure 2. (a) Refractive index n and extinction coefficient k of $(MA_{0.13}FA_{0.87})PbI_3$ at room temperature. (b) Optical absorption coefficient of $(MA_{0.13}FA_{0.87})PbI_3$ at room temperature. The inset presents the room-temperature photoluminescence spectrum of $(MA_{0.13}FA_{0.87})PbI_3$.

The spectroscopic ellipsometry analysis fitting results are shown in the Supplementary Information. The surface roughness is around 10.8 nm and the mean square error (MSE) is 0.86.

Results and Discussion

Figure 1 illustrates the room temperature x-ray diffraction pattern of $(MA_{0.13}FA_{0.87})PbI_3$. All of the reflections could be indexed, and no impurity phases were apparent above the background level. Additionally, the spectra matched well with those previously observed^{19–22}. A previously study on mixed-halide perovskites reported peaks at 11.63° and 12.85°, which were attributed to the α -phase of FAPbI₃ and cubic PbI₂^{19–22}. However, no such peaks were observed in the x-ray diffraction pattern in this study, indicating the high purity of our single crystals. Rietveld refinement results of $(MA_{0.13}FA_{0.87})PbI_3$ revealed a cubic structure belonging to the Pm-3m space group with the lattice parameter of a = 6.439 Å.

Figure 2(a) presents the room temperature refractive index n and extinction coefficient k of $(MA_{0.13}FA_{0.87})$ PbI₃, which were obtained through spectroscopic ellipsometry analysis. The room temperature experimental ellipsometric and best-fit calculated data of (MA_{0.13}FA_{0.87})PbI₃ were shown in the Supplementary Information. These data were almost identical by rotating the sample's azimuthal orientation of 45° and 90° shown in the Supplementary Information, indicating the isotropic optical properties of the sample. Dispersion of the refractive index n as a function of frequency is typical of a semiconductor. Optical transitions were identified in the spectra according to resonance and antiresonance features that appeared at the same energy in k and n, respectively. Specifically, the extinction coefficient spectrum k of (MA_{0.13}FA_{0.87})PbI₃ was dominated by several optical transitions. We calculated the optical absorption coefficient α by $\alpha = 4\pi k/\lambda$, where k is the extinction coefficient and λ is the wavelength. Figure 2(b) displays the room temperature optical absorption spectrum of (MA_{0.13}FA_{0.87}) PbI₃. In the inset of Fig. 2(b), we present the room-temperature photoluminescence spectrum, which exhibited a strong luminescence signal at approximately 1.50 eV. On the basis of previous reports^{14,15}, Wright et al.¹⁴ presented the room temperature photoluminescence peaks of FAPbI3 and MAPbI3 at approximately 1.53 and 1.60 eV and Dar et al.¹⁵ found the room temperature photoluminescence peak of MAPbI₃ at approximately 1.61 eV. The observed strong luminescence peak at approximately 1.50 eV for (MA_{0.13}FA_{0.87})PbI₃ is associated with the exciton transition.

Figure 3(a,b) illustrates the temperature dependence of the refractive index n and the extinction coefficient k of $(MA_{0.13}FA_{0.87})PbI_3$. As the temperature decreased, the refractive index increased in the visible and near-infrared-frequency region. The room-temperature thermo-optic coefficients of the refractive index (dn/dT) were approximately -1.7×10^{-4} and -2.5×10^{-4} K⁻¹ at wavelength of 600 and 1200 nm. This behavior differs from

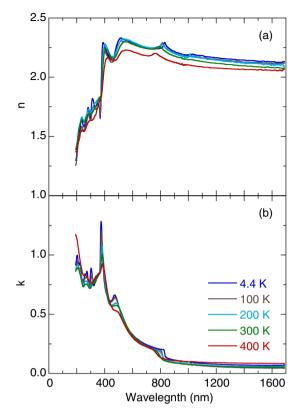


Figure 3. Temperature dependence of the (a) refractive index and (b) extinction coefficient spectra of $(MA_{0.13}FA_{0.87})PbI_{3}$.

that known for conventional semiconductors such as silicon, which shows a positive value for the thermo-optic coefficient²³. According to Ghosh's model^{24,25}, dn/dT can be expressed as follows:

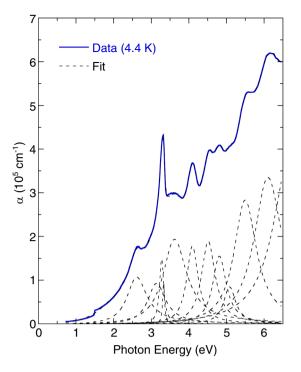
$$\frac{dn}{dT} = A \left(-3\alpha R - \frac{1}{E_{eg}} \frac{dE_{eg}}{dT} R^2 \right),\tag{3}$$

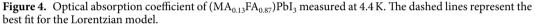
where $A = (n^2 - 1)/2n$, is the linear thermal expansion coefficient, E_{eg} is the excitonic bandgap, and $R = \lambda^2/(\lambda^2 - 1)/2n$ λ_{ig}^2) is the normalized dispersive wavelength (λ_{ig} : wavelength corresponding to the isentropic bandgap). In the case of halide perovskites, the first term is negative because the thermal expansion coefficient is positive, and the second term is negative due to positive dE_{ee}/dT . As a results, $(MA_{0.13}FA_{0.87})PbI_3$ exhibits the negative value of the thermo-optic coefficient. A similar tendency for temperature dependence has been detected in the refractive index of TiO_2 thin films²⁶ and KTaO₃ single crystals²⁷. In the present study, the extinction coefficient spectra indicated that the absorption features became sharper and shifted to a higher energy. Figure 4 depicts the optical absorption spectrum of (MA_{0.13}FA_{0.87})PbI₃ at 4.4 K. This absorption spectrum was modeled reasonably well using the Lorentzian oscillators. The peak energy and assignment are summarized in Table 1. In accordance with previous reports¹⁰⁻¹⁵, the first absorption peak near 1.50 eV was assigned to the exciton transition. The absorption peaks at approximately 2.61, and 3.13 eV were associated with the charge-transfer excitations of the N 2p orbital to the I 5p orbital. The absorption peak at approximately 3.33 eV was attributed to the charge-transfer excitation of the I 5p orbital to the Pb 5p orbital. The absorption peaks near 3.62 and 4.09 eV were attributed to the charge-transfer excitations of the C 2p orbital to the I 5p orbital. Additionally, the absorption peaks at approximately 4.51, 4.81, 5.08, and 5.50 eV were associated with the charge-transfer excitations of I 5p orbital to Pb 6p orbital

In order to analyze the temperature-dependent exciton transition and bandgap energy, we have fitted the low-energy portion of the optical absorption spectra using the Elliott formula^{28,29}

$$\begin{aligned} \alpha(E) &= \left[A \cdot \theta(E - E_g) \cdot D_{CGV}(E) \right] \left[\frac{\pi x e^{\pi x}}{\sinh(\pi x)} \right] \\ &+ A \cdot R_x \cdot \sum_{n=1}^{\infty} \frac{4\pi}{n^3} \cdot \delta(E - E_g + R_x/n^2), \end{aligned}$$
(4)

where *A* is a constant, *E* is the photon energy, E_g is the bandgap energy, θ is the step function, D_{CV} is the joint density of states described as $D_{CV} \sim (E - E_g)$ near the direct band edge, *n* is the principal quantum number of the exciton state, δ presents a delta function, and $x = [R_x/(E - E_g)]$, with R_x being the exciton binding energy.





Peak energy (eV)		Assignment
ω	1.50	Exciton
ω2	2.61	N 2p — I 5p
ω	3.13	
ω_4	3.33	I 5p — Pb 5p
ω ₅	3.62	C 2p — I 5p
ω ₆	4.09	
ω ₇	4.51	I 5p — Pb 6p
ω ₈	4.81	
ω ₉	5.08	
ω_{10}	5.50	

Table 1. Optical transitions observed at 4.4 K with their corresponding assignments.

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Figure 5(a) presents the temperature-dependent exciton absorption spectra of $(MA_{0.13}FA_{0.87})PbI_3$. Figure 5(b) shows the absorption edge and excitonic contribution fitting results using the Elliott formula. The background was fitted with the standard Lorentzian profile. The values of E_g (\approx 1.53 and 1.66 eV) and R_x (\approx 16 and 40 meV) were determined at 4.4 and 300 K, respectively. Figure 6(a) denotes the temperature-dependent exciton peak position and bandgap energy of $(MA_{0.13}FA_{0.87})PbI_3$. The unusual redshift can be attributed to a reverse ordering of the electronic band structure¹³. Additionally, anomalous behavior in exciton peak position and bandgap energy was observed at 100–200 K due to the structural phase transition. This phenomenon was associated with the coexistence of MA/FA-disordered and MA/FA-ordered domains¹⁵.

The temperature-dependent exciton binding energy is shown in Fig. 6(b). At high temperature phase, the exciton binding energy of $(MA_{0.13}FA_{0.87})PbI_3$ is around 40 meV. It decreases to 16 meV at 4.4 K. Our room temperature results are close to the values predicted by the first-principles calculations $(MAPbI_3 \sim 45 \text{ meV} \text{ and } FAPbI_3 \sim 35 \text{ meV})^{30}$. Notably, the exciton binding energy of $(MA_{0.13}FA_{0.87})PbI_3$ decreases when the temperature is lowered. This trend is similar with the previous absorption and photoluminescence measurements of MAPbI_3 reported by S. Singh *et al.*³¹. The exciton binding energy of MAPbI_3 was approximately 30 and 15 meV at high temperature tetragonal phase and low temperature orthorhombic phase, respectively. However, our results are different from the previous photoluminescence, photoabsorption, and magneto-transmission measurements in MAPbI_3. Y. Yamada *et al.* reported the exciton binding energy of MAPbI_3 to be approximately 6 and 30 meV at room temperature and 13 K, respectively³². A. Miyata *et al.* measured a value of the exciton binding energy of MAPbI_3 to be a few meV at room temperature, but 16 meV in the low temperature orthorhombic phase³³. Further theoretical work is needed to clarify the discrepancy of the experimental data.

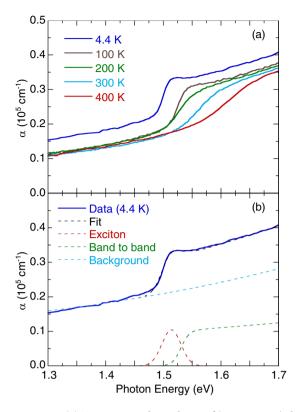


Figure 5. (a) Temperature dependence of $(MA_{0.13}FA_{0.87})PbI_3$ exciton absorption spectra. (b) The absorption edge of $(MA_{0.13}FA_{0.87})PbI_3$ measured at 4.4 K. The dashed lines are the best fit using the Elliott formula.

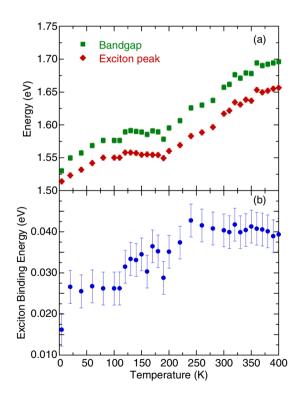
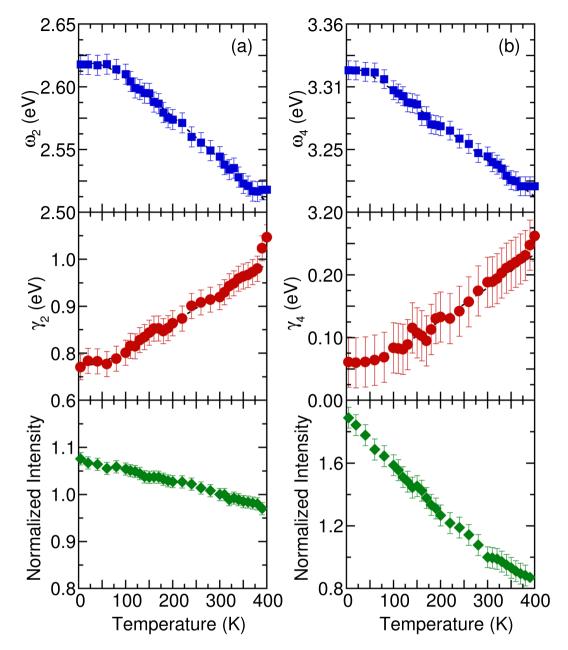


Figure 6. (a) Bandgap energy and peak position of exciton in $(MA_{0.13}FA_{0.87})PbI_3$ as a function of temperature. (b) Temperature dependence of exciton binding energy in $(MA_{0.13}FA_{0.87})PbI_3$.



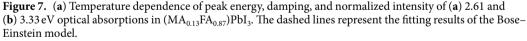


Figure 7 denotes the peak energy, damping, and normalized intensity of 2.61 and 3.33 eV optical transitions as a function of temperature. The temperature-dependent parameters of other optical transitions are shown in the Supplementary Information. The observed increase in the peak energy and decrease of damping with decreasing temperature can be described using the Bose–Einstein model³⁴.

$$E = a - b \left[1 + \frac{2}{e^{\frac{\Theta}{T}} - 1} \right], \tag{5}$$

and

$$\Gamma = \Gamma_0 \left[1 + \frac{2}{e^{\Theta} - 1} \right] + \Gamma_1 \tag{6}$$

where *a* and Γ_1 are the transition energy and linewidth at 0 K; *b* and Γ_0 represent the strength of the electron-phonon interactions; and Θ is the average phonon temperature. For the analysis of 2.61 eV electronic excitation,

the values of $a (\approx 2.62 \text{ eV})$, $b (\approx 28 \text{ meV})$, $\Gamma_1 (\approx 0.72 \text{ eV})$, $\Gamma_o (\approx 302 \text{ meV})$, and $\Theta (\approx 201 \text{ K})$ were determined. For the analysis of the 3.33 eV electronic excitation, the values of $a (\approx 3.34 \text{ eV})$, $b (\approx 12 \text{ meV})$, $\Gamma_1 (\approx 0.14 \text{ eV})$, $\Gamma_o (\approx 112 \text{ meV})$, and $\Theta (\approx 240 \text{ K})$ were determined. The dashed lines in Fig. 7(a,b) represent theoretical predictions based on Eqs. (5, 6). These two optical transitions exhibited a slight deviation from the Bose-Einstein predictions to the temperature dependence of the peak position and linewidth between 100 and 200 K due to the structural phase transition.

Summary

We investigated the temperature-dependent optical properties of $(MA_{0.13}FA_{0.87})PbI_3$ single crystals using spectroscopic ellipsometry. The absorption emerging in extinction coefficient spectrum indicated that $(MA_{0.13}FA_{0.87})PbI_3$ has a direct band gap of $1.66 \pm 0.05 \text{ eV}$ with a large exciton binding energy of 40 meV. With decreasing temperature, the refractive index increased. The room-temperature thermo-optic coefficients were -1.7×10^{-4} and $-2.5 \times 10^{-4} \text{ K}^{-1}$ at wavelength of 600 and 1200 nm. The exciton transition and bandgap energy demonstrated sensitivity to the structural phase transition at 100–200 K. The data presented in this study offer insights into the design and fabrication of lead halide perovskites-based photonic devices for integrated optics and solar cell applications at various temperatures.

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Author contributions

H.L.L. conceived the idea and designed the experiments. H.W.C. performed the experiments. D.P.G. and Y.C.C. prepared the samples. H.W.C. and H.L.L. wrote the paper. All the authors discussed the results and commented on the manuscript.

Competing interests

The authors declare no competing interests.

Additional information

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